

XN05531 (XN5531)

Silicon NPN epitaxial planer transistor

For high frequency oscillation and mixing

Features

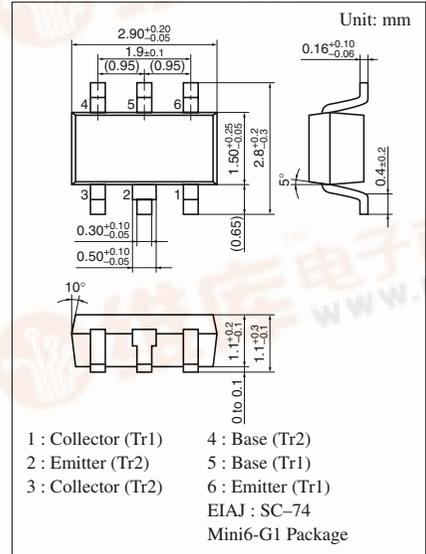
- Two elements incorporated into one package.
- Reduction of the mounting area and assembly cost by one half.

Basic Part Number of Element

- 2SC3130 × 2 elements

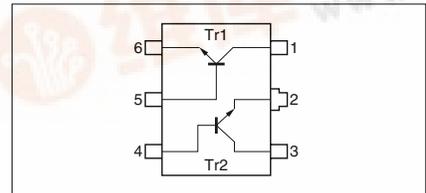
Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Ratings	Unit
Rating of element	Collector to base voltage	V_{CBO}	15	V
	Collector to emitter voltage	V_{CEO}	10	V
	Emitter to base voltage	V_{EBO}	3	V
	Collector current	I_C	50	mA
Overall	Total power dissipation	P_T	200	mW
	Junction temperature	T_j	150	°C
	Storage temperature	T_{stg}	-55 to +150	°C



Marking Symbol: 5M

Internal Connection



Electrical Characteristics (Ta=25°C)

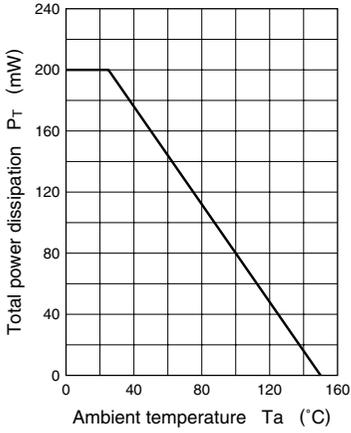
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector to emitter voltage	V_{CEO}	$I_C = 2\text{mA}, I_B = 0$	10			V
Emitter to base voltage	V_{EBO}	$I_E = 10\mu\text{A}, I_C = 0$	3			V
Collector cutoff current	I_{CBO}	$V_{CB} = 10\text{V}, I_E = 0$			1	μA
	I_{CEO}	$V_{CE} = 10\text{V}, I_B = 0$			10	μA
Forward current transfer ratio	h_{FE1}	$V_{CE} = 4\text{V}, I_C = 5\text{mA}$	75	200	400	
Forward current transfer h_{FE} ratio	$h_{FE}(\text{small/large})^1$	$V_{CE} = 4\text{V}, I_C = 5\text{mA}$	0.5	0.99		
h_{FE2}/h_{FE1} ratio	h_{FE2}/h_{FE1}	$V_{CE} = 4\text{V}, I_C = 100\mu\text{A}$ $V_{CE} = 4\text{V}, I_C = 5\text{mA}$	0.75		1.6	
Collector to emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C = 20\text{mA}, I_B = 4\text{mA}$			0.5	V
Collector output capacitance	C_{ob}	$V_{CB} = 4\text{V}, I_E = 0, f = 1\text{MHz}$		0.9	1.1	pF
Transition frequency	f_T	$V_{CB} = 4\text{V}, I_E = -5\text{mA}, f = 200\text{MHz}$	1.4	1.9	2.5	GHz
Collector to base parameter	$r_{bb}' \cdot C_C$	$V_{CB} = 4\text{V}, I_E = -5\text{mA}, f = 30\text{MHz}$		11.8	13.5	ps
Common base reverse transfer capacitance	C_{rb}	$V_{CB} = 4\text{V}, I_E = 0, f = 1\text{MHz}$		0.25	0.35	pF

Ratio between 2 elements

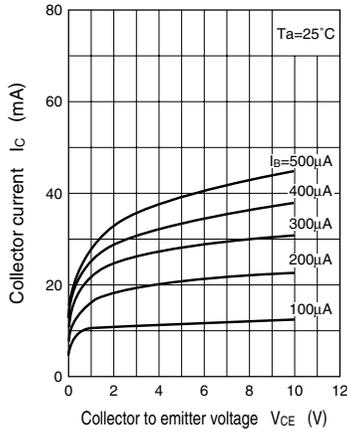
Note) The Part number in the Parenthesis shows conventional part number.



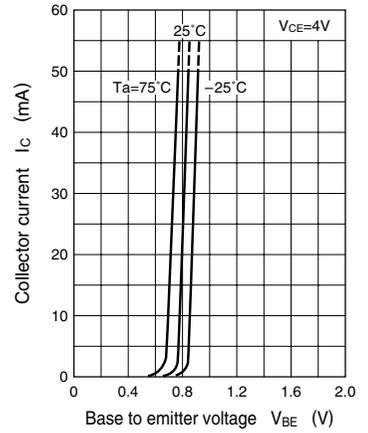
$P_T - T_a$



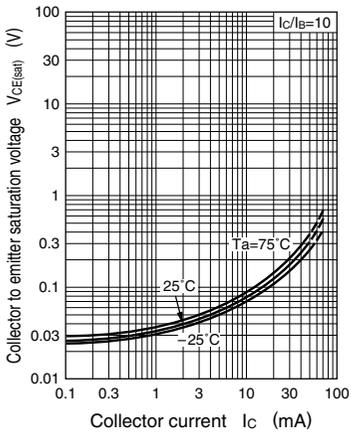
$I_C - V_{CE}$



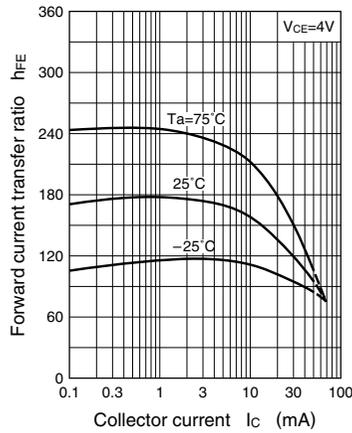
$I_C - V_{BE}$



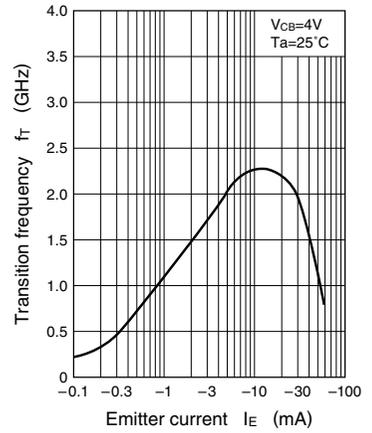
$V_{CE(sat)} - I_C$



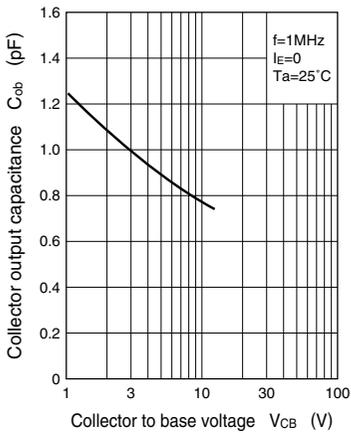
$h_{FE} - I_C$



$f_T - I_E$



$C_{ob} - V_{CB}$



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